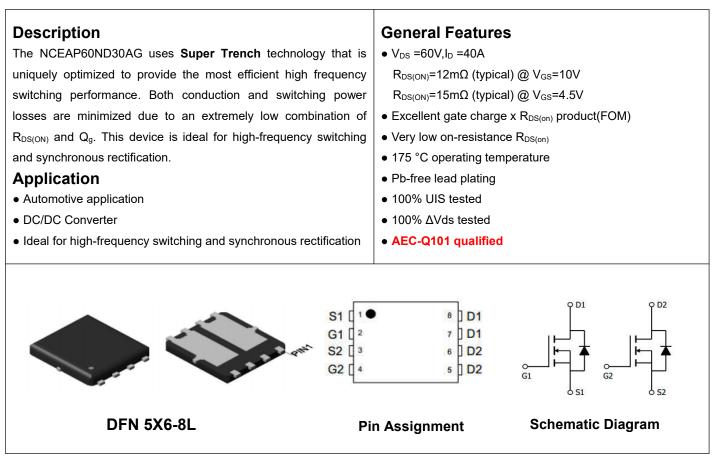


## NCE Automotive N-Channel Super Trench Power MOSFET



### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP60ND30AG	NCEAP60ND30AG	DFN5x6-8L	-	-	-

### Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	  (100℃) 	40	A
Brain Guirein-Gontinuous	l₀(100℃)	30	A
Pulsed Drain Current	Ідм	120	A
Maximum Power Dissipation	PD	48	W
Derating factor		0.32	W/℃
Single pulse avalanche energy (Note 2)	E <sub>AS</sub>	135	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case	Rejc	3.13	°C/W	
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## Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	I		<b>-</b>			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	60		-	V
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics	· · ·					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.2	1.7	2.2	V
Durain Course On Chata Desistance	_	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	12.0	14.0	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =4.5V, $I_D$ =20A	-	15.0	17.5	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =20A		40	-	S
Dynamic Characteristics	· · ·					
Input Capacitance	Clss		-	1010	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V, F=1.0MHz	-	183.2	-	pF
Reverse Transfer Capacitance	Crss		-	9.9	-	pF
Switching Characteristics (Note 1)	· · ·					
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =30V,I <sub>D</sub> =20A V <sub>GS</sub> =10V,R <sub>G</sub> =1.6Ω	-	11	-	nS
Turn-on Rise Time	tr		-	17	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	18	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg	V -20V/L -20A	-	21.8	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =30V,I <sub>D</sub> =20A,	-	4.6		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	3.5		nC
Drain-Source Diode Characteristics	· · ·			· I		
Diode Forward Voltage	Vsd	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-		1.2	V
Diode Forward Current	Is		-	-	30	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> = I <sub>S</sub>	-	30	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	36	-	nC

#### Notes:

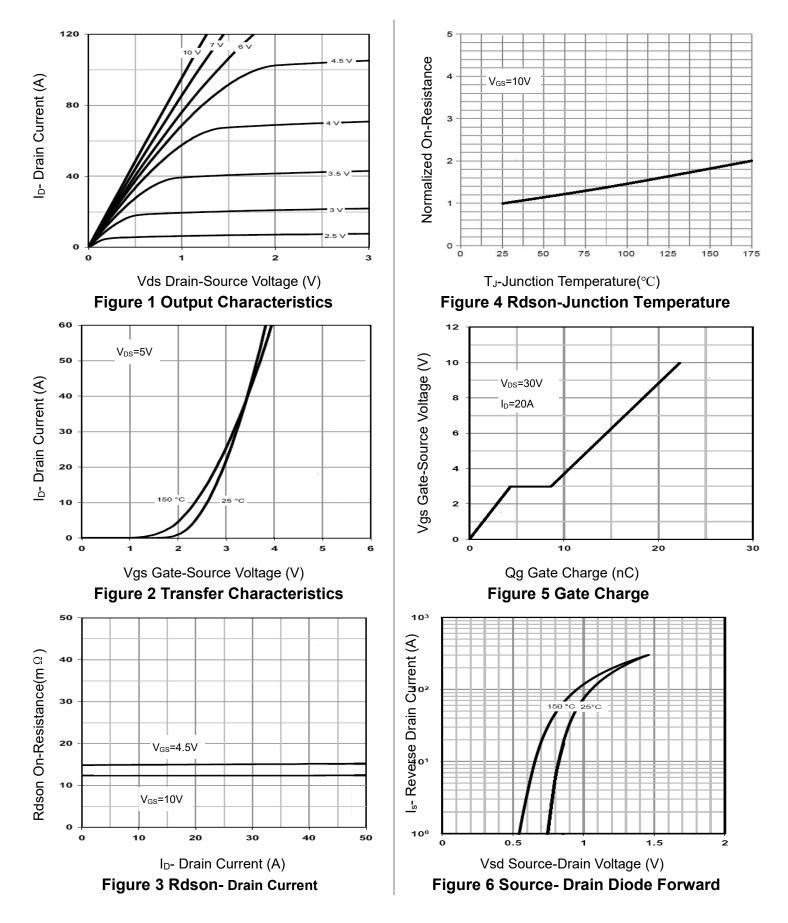
1. Defined by design.Not Subject to production test

2. EAS condition : Tj=25  $^\circ \!\!\! C$  ,V\_DD=30V,V\_G=10V,L=0.5mH,Rg=25  $\Omega$ 

3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.



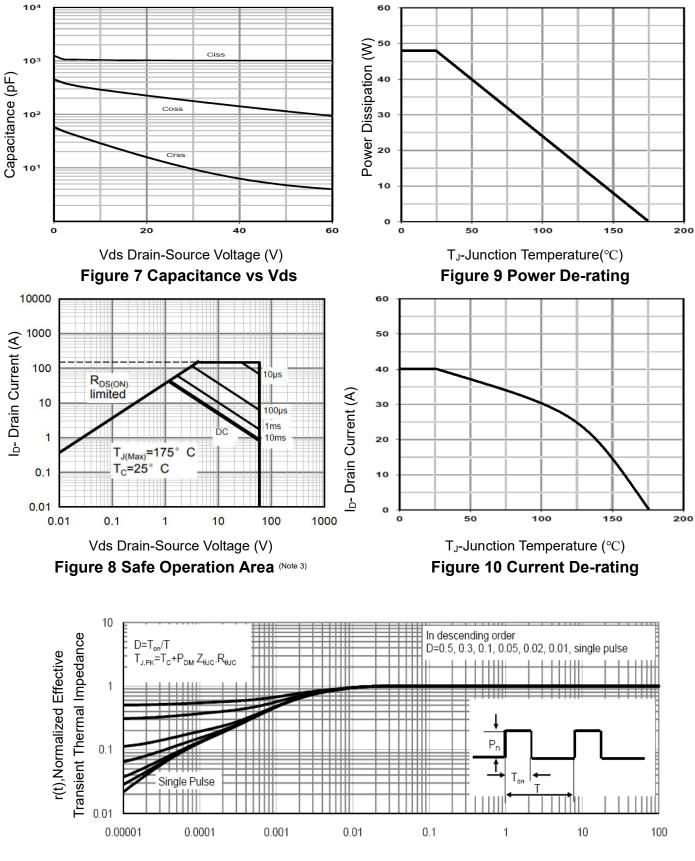
## **Typical Electrical and Thermal Characteristics**





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# NCEAP60ND30AG

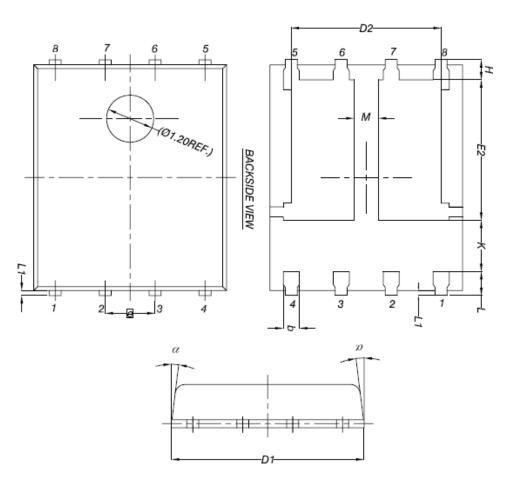


Square Wave Pluse Duration(sec)

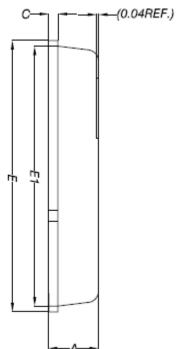
## Figure 11 Normalized Maximum Transient Thermal Impedance



# DFN5X6-8L Package Information



	MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	
Α	0.90	1.00	1.10	
b	0.33	0.41	0.51	
С	0.20	0.25	0.30	
D1	4.80	4.90	5.00	
D2	3.61	3.81	3.96	
E	5.90	6.00	6.10	
E1	5.70	5.75	5.80	
E2	3.38	3.58	3.78	
е	1.27 BSC			
н	0.41	0.51	0.61	
к	1.10	-	-	
L	0.51	0.61	0.71	
L1	0.06	0.13	0.20	
м	0.50	-	-	
α	0°	-	12°	





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